NSN 5961-00-113-4931

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View Online at https://aerobasegroup.com/nsn/5961-00-113-4931 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Overall Diameter:** 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: -40.0 collector to emitter voltage, dc with specified circuit between base and emitter and -30.0 collector to emitter voltage/static/base open and -30.0 collector to emitter voltage, dc and -2.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: